## NSN 5961-01-303-4841

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View Online at https://aerobasegroup.com/nsn/5961-01-303-4841 **Inclosure Material:** Metal **Overall Length:** 38.31 millimeters **Terminal Length:** 7.93 millimeters **Overall Height:** 11.4 millimeters **Overall Width:** 13.33 millimeters **Mounting Facility Quantity: Internal Configuration:** Junction contact-darlington connected Joint Electronic Device Engineering Council/jedec/case Outline Designation: Y204a **Mounting Method:** Terminal and unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 breakdown voltage, collector-to-base, emitter open and 400.0 breakdown voltage, collector-to-emitter, base open and 8.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 10.00 amperes source cutoff current and 2.00 amperes source cutoff current **Power Rating Per Characteristic:** 175.0 watts small-signal input power, common-collector **Transfer Ratio:** 100.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a

No

**Unit Of Measure:** 

Demilitarization:

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